NSN 5961-01-170-2163

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View Online at https://aerobasegroup.com/nsn/5961-01-170-2163 **Inclosure Material:** Plastic **Overall Length:** 1.145 inches **Terminal Length:** 0.540 inches **Overall Height:** 0.165 inches **Overall Width:** 0.400 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Terminal and unthreaded hole Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current and 0.20 amperes source cutoff current **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 70.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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